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	APPLICANT YUASA	
	FILING DATE September 8, 2006	GROUP 2827

## U.S. Patent Documents

Examiner Initial	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
	2007/0128470	6/7/2007	Nagahama et al.			2/12/2007
	2004/0144995	7/29/2004	Nagahama et al.			5/24/2002
	2004/0245553	12/9/2004	Hosomi et al.			4/8/2003
	2006/0056115	3/16/2006	Djayaprawira et al.			9/7/2005

## Foreign Patent Documents

Examiner Initial	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLA SS	SUB-CLASS	TRANSLATION	
						YES	No
	2003-318465*	4/23/2002	Japan			Abstract	
	WO 2002/099905	5/24/2002	PCT			Abstract	
	EP 1 391 942	5/24/2002	EP			X	
	2002-204004	12/28/2000	Japan			Abstract	X
	2002-289943	3/26/2001	Japan			Abstract	X
	2003-304010**	4/9/2002	Japan			Abstract	
	WO 2003/085750	4/8/2003	PCT			Abstract	
	EP 1 494 295	4/8/2003	EP			X	
	2006-080116***	9/7/2004	Japan			Abstract	

\* Corresponds to U.S. Patent 2007/0128470, U.S. Patent 2004/0144995, WO2002/099905, and EP1 391 942, listed above.

\*\* Corresponds to U.S. Patent 2004/0245553, WO 2003/085750, and EP 1 494 295, listed above.

\*\*\* Corresponds to U.S. Patent 2006/0056115, listed above.

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

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EXAMINER		DATE CONSIDERED
<p><i>EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant</i></p>		

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